



CHENMKO ENTERPRISE CO.,LTD

**SURFACE MOUNT
Dual Silicon Transistor**

VOLTAGE 50 Volts CURRENT 150 mAmpere

CHEMX3GP

Halogens free devices

APPLICATION

- * Small Signal Amplifier .

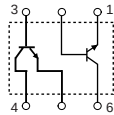
FEATURE

- * Small surface mounting type. (SOT-563)
- * Low saturation voltage $V_{CE(sat)}=0.4V(max.)$ ($I_C=50mA$)
- * Low cob. $C_{ob}=2.0pF(Typ.)$
- * $P_C=150mW$ (Total),120mW per element must not be exceeded.
- * High saturation current capability.
- * Two the 2SC2412K in one package.
- * NPN Silicon Transistor

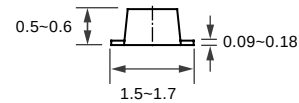
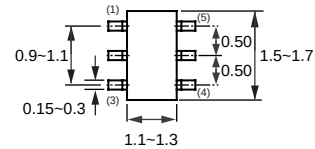
MARKING

- * X3

CIRCUIT



SOT-563



Dimensions in millimeters

SOT-563

2SC2412K LIMITING VALUES

MAXIMUM RATINGS (At $T_A = 25^{\circ}C$ unless otherwise noted)

RATINGS	CONDITION	SYMBOL	MIN.	MAX.	UNITS
Collector - Base Voltage	Open Emitter	V_{CBO}	-	60	Volts
Collector - Emitter Voltage	Open Base	V_{CEO}	-	50	Volts
Emitter - Base Voltage	Open Collector	V_{EBO}	-	7	Volts
Collector Current DC		I_C	-	150	mAmps
Peak Collector Current		I_{CM}	-	150	mAmps
Peak Base Current		I_{BM}	-	15	mAmps
Total Power Dissipation	$T_A \leq 25^{\circ}C$; Note 1	P_{TOT}	-	150	mW
Storage Temperature		T_{STG}	-55	+150	$^{\circ}C$
Junction Temperature		T_J	-	+150	$^{\circ}C$
Operating Ambient Temperature		T_{AMB}	-55	+150	$^{\circ}C$

Note

1. Transistor mounted on ceramic substrate 50mmX50mmX0.8t.

RATING CHARACTERISTIC CURVES (CHEMX3GP)

2SC2412K CHARACTERISTICS

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

PARAMETERS	CONDITION	SYMBOL	MIN.	TYPE	MAX.	UNITS
Collector-base breakdown voltage	IC=50uA	BVCBO	60	-	-	Volts
Collector-emitter breakdown voltage	IC=1mA	BVCEO	50	-	-	Volts
Emitter-base breakdown voltage	IE=50uA	BVEBO	7	-	-	Volts
Collector Cut-off Current	IE=0; VCB=60V	ICBO	-	-	0.1	
Emitter Cut-off Current	IC=0; VEB=7V	ICEO	-	-	0.1	uA
DC Current Gain	VCE=6V IC=1mA	hFE	120	-	560	
Collector-Emitter Saturation Voltage	IC=50mA; IB=5mA	VCEsat	-	-	0.4	Volts
Output Collector Capacitance	IE=IE=0; VCB=12V; f=1MHz	Cob	-	2	3.5	pF
Transition Frequency	IC=2mA; VCE=12V; f=100MHz	fT	-	180	-	MHz

RATING CHARACTERISTIC CURVES (CHEMX3GP)

2SC2412K Typical Electrical Characteristics

Fig.1 Grounded emitter propagation characteristics

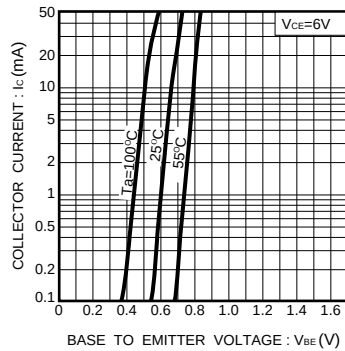


Fig.2 Grounded emitter output characteristics

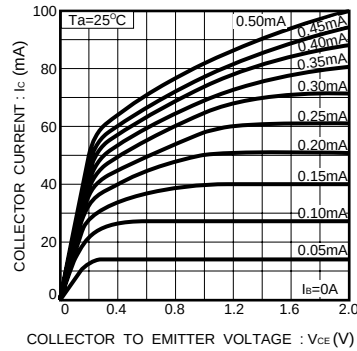


Fig.3 DC current gain vs. collector current (1)

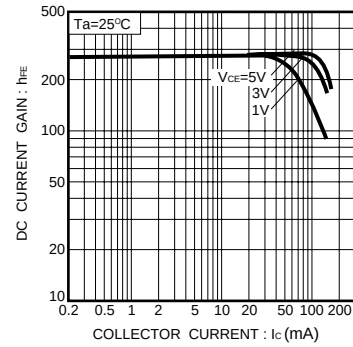


Fig.4 DC current gain vs. collector current (2)

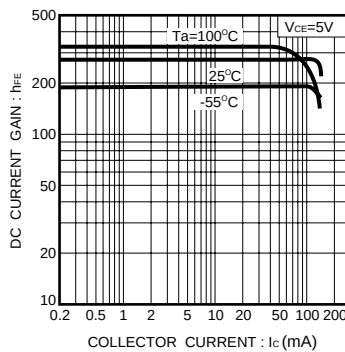


Fig.5 Collector-emitter saturation voltage vs. collector current

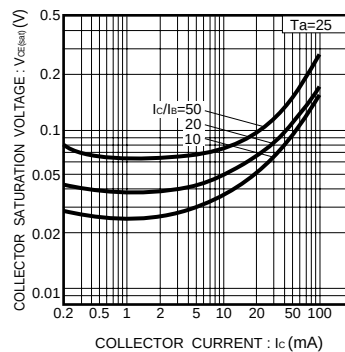


Fig.6 Collector-emitter saturation voltage vs. collector current

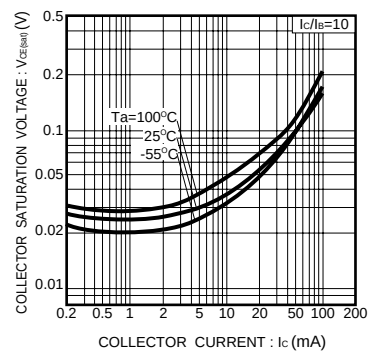


Fig.7 Gain bandwidth product vs. emitter current

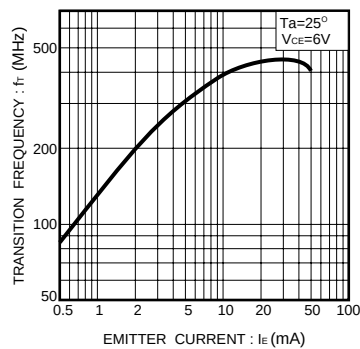


Fig.8 Base-collector time constant vs. emitter current

